



## NON BASE LEAD OPTICALLY COUPLED ISOLATOR PHOTODARLINGTON OUTPUT



### APPROVALS

- UL recognised, File No. E91231

### DESCRIPTION

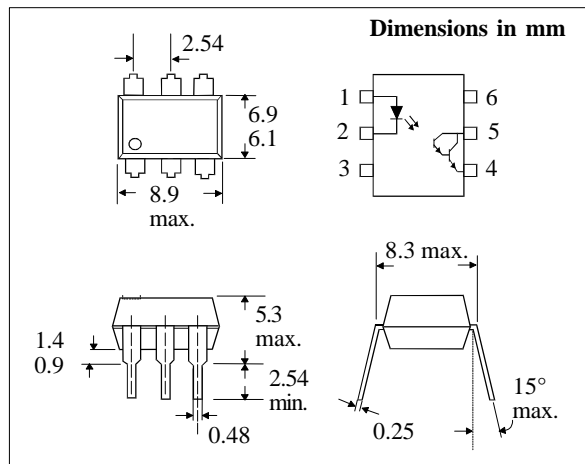
The ISPD6\_ series of optically coupled isolators consist of an infrared light emitting diode and NPN silicon photodarlington in a standard 6pin dual in line plastic package with the base pin unconnected.

### FEATURES

- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (500% min)
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- Basepin unconnected for improved noise immunity in high EMI environment
- High sensitivity to low input drive current
- Custom electrical selections available

### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances



### ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise specified)

Storage Temperature \_\_\_\_\_ -55°C to + 150°C  
 Operating Temperature \_\_\_\_\_ -55°C to + 100°C  
 Lead Soldering Temperature  
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

### INPUT DIODE

Forward Current \_\_\_\_\_ 60mA  
 Reverse Voltage \_\_\_\_\_ 5V  
 Power Dissipation \_\_\_\_\_ 120mW

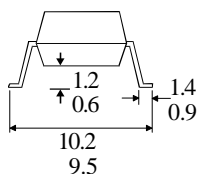
### OUTPUT TRANSISTOR

Collector-emitter Voltage  $BV_{CEO}$  \_\_\_\_\_ 30V  
 Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 5V  
 Power Dissipation \_\_\_\_\_ 150mW

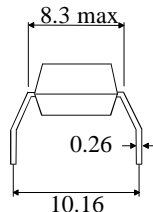
### POWER DISSIPATION

Total Power Dissipation \_\_\_\_\_ 250mW  
 (derate linearly 3.3mW/°C above 25°C)

#### OPTION SM SURFACE MOUNT



#### OPTION G



### ISOCOM COMPONENTS LTD

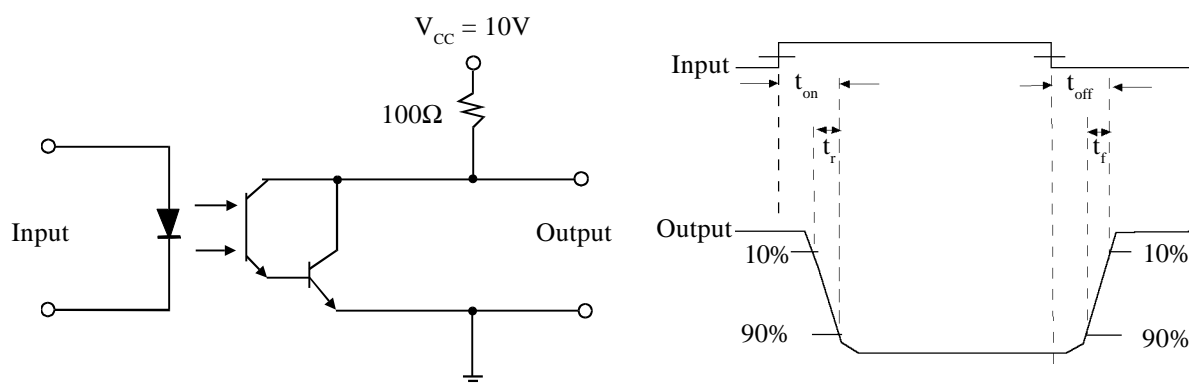
Unit 25B, Park View Road West,  
 Park View Industrial Estate, Brenda Road  
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**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION	
Input	Forward Voltage ( $V_F$ )		1.2	1.5	V	$I_F = 10\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 3\text{V}$	
	Reverse Voltage ( $V_R$ )	3			V		
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$		
Output	Collector-emitter Breakdown ( $BV_{CEO}$ )	30			V	$I_C = 1\text{mA}$ (note 2) $I_E = 100\mu\text{A}$ $V_{CE} = 10\text{V}$	
	Emitter-collector Breakdown ( $BV_{ECO}$ )	5			V		
	Collector-emitter Dark Current ( $I_{CEO}$ )			100	nA		
Coupled	Current Transfer Ratio (CTR) (Note 2)					$1\text{mA } I_F, 2\text{V } V_{CE}$ $1\text{mA } I_F, 2\text{V } V_{CE}$ $1\text{mA } I_F, 2\text{V } V_{CE}$	
	ISPD60, ISPD63	100			%		
	ISPD61, ISPD64	500			%		
	ISPD62, ISPD65	1000			%		
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			1.0	V		$10\text{mA } I_F, 10\text{mA } I_C$
	Input to Output Isolation Voltage $V_{ISO}$	5300			$V_{RMS}$		(note 1)
		7500			$V_{PK}$		(note 1)
	Input-output Isolation Resistance $R_{ISO}$	$10^{11}$			$\Omega$		$V_{IO} = 500\text{V}$ (note 1)
	Output Rise Time $t_r$		60		$\mu\text{s}$		$V_{CC} = 10\text{V}, I_C = 2\text{mA},$ $R_L = 100\Omega$ , fig.1
	Output Fall Time $t_f$		60		$\mu\text{s}$		
Delay Time $t_d$		10		$\mu\text{s}$			
Storage Time $t_s$		3		$\mu\text{s}$			

- Note 1 Measured with input leads shorted together and output leads shorted together.  
 Note 2 Special Selections are available on request. Please consult the factory.

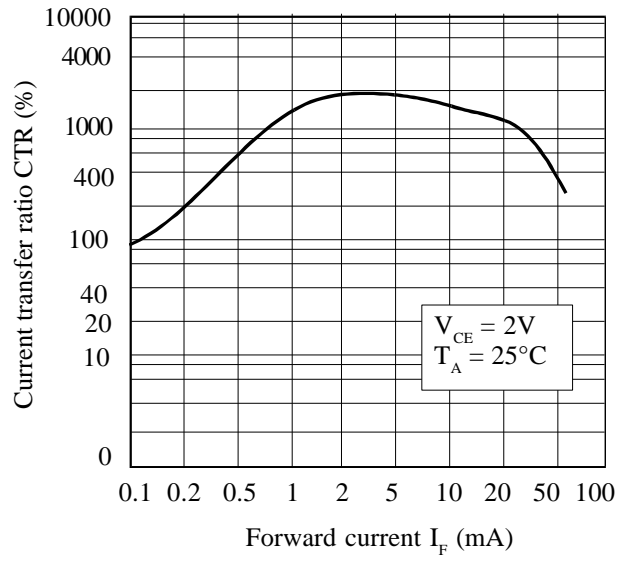
**FIGURE 1**



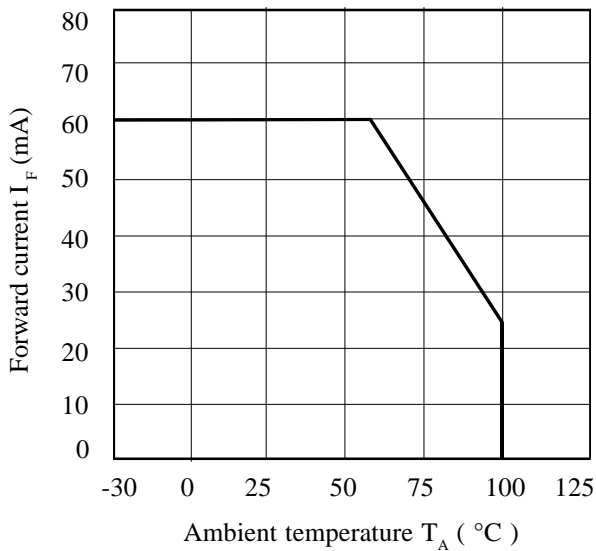
**Collector Power Dissipation vs. Ambient Temperature**



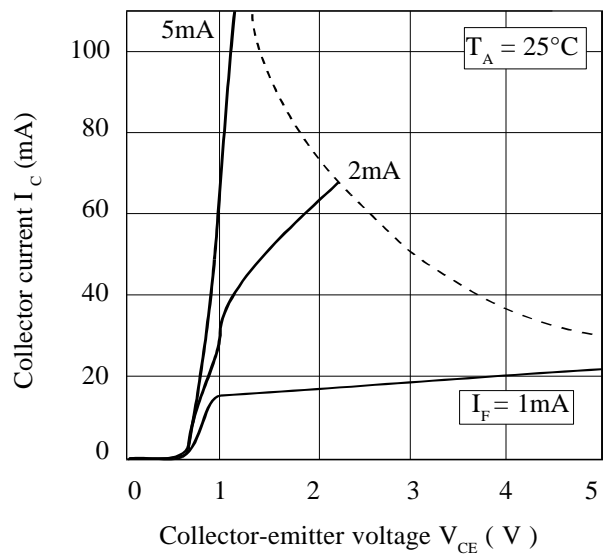
**Current Transfer Ratio vs. Forward Current**



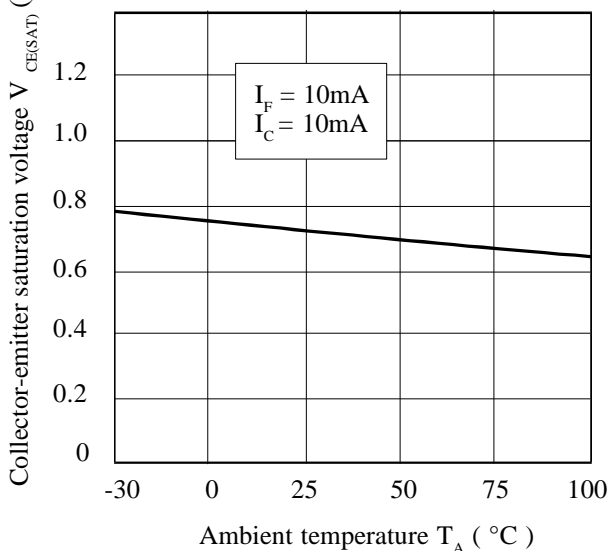
**Forward Current vs. Ambient Temperature**



**Collector Current vs. Collector-emitter Voltage**



**Collector-emitter Saturation Voltage vs. Ambient Temperature**



**Normalized Current Transfer Ratio vs. Ambient Temperature**

